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Wrap-up & Legacy

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Beyond 2020: E³S Legacy Update Report

- 1. Berkeley Emerging Technology and Research (BETR) Center
- 2. Negative Capacitance Industry-Supported Center
- 3. Graphene Nanoribbons MURI
- 4. Semiconductor Research Corporation (SRC) JUMP Centers
- 5. Nanophotonics NSF ERC Proposal





Beyond 2020: E³S Legacy Update Report-Education Legacy

- 1. E3S e-Book
- 2. E3S nanoHUB Website
- 3. TTE Renewal Grant
- 4. Third-Party Support
- 5. TTE-2.0 Proposal





Research Legacy on Future Technology:

In addition to a legacy represented by continuing research organizations, E³S prides itself on the scientific influence it will continue to have on the future science & technology of energy efficient electronics.

Theme 1 has found that tunnel-Field Effect Transistors will be much more challenging to create, than expected. Nonetheless, Theme 1 has laid out the requirements that will guide future research, including atomic scale perfection, and non-Lorentzian spectral lineshape, arising from narrow-band metallic, organically synthesized graphene nano-ribbons.

Theme 2 has demonstrated the importance of molecular functionalization on the surfaces of nano-electro-mechanical switches, that will likely become standard in the field of nano-mechanics.

Theme 3 has shown that the antenna-LED is the missing link of opto-electronic souces for onchip optical communication. The antenna-LED operates at low power, but at a speed faster than lasers.

Theme 4 has shown the correct path for high-speed magnetic switching, increasing switching speed by 100×, down to the picosecond range.



